Diode Semiconductor Device - Page 1 of 1



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Inclosure Mater	181:
Glass	
Overall Length:	
Between 0.195 i	nches and 0.350 inches
Terminal Lengt	h:
1.000 inches	
Overall Diamete	er:
Between 0.215 i	nches and 0.265 inches
Electrode Interi	nally-electrically Connected To Case:
Cathode	
Mounting Methe	od:
Terminal	
Features Provid	led:
Hermetically sea	led case
Semiconductor	Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
7.1 regulator vo	ltage
Current Rating	Per Characteristic:
140.00 milliampe	eres source cutoff current horsepower metric
Power Rating P	er Characteristic:
1.0 watts small-s	ignal input power, common-collector preset
Maximum Oper	ating Tempurature Per Measurement Point:
175.0 degrees c	elsius ambient air
Test Data Docu	ment:
81349-mil-s-195	00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificati
format; exclude:	s commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental a	nd performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type	And Quantity:
2 uninsulated wi	re lead
Specification D	ata:
81349-mil-s-195	00/115 government specification
Shelf Life:	
N/a	
Unit Of Measur	9:
Demilitarization	
No	
Fiig:	
A110a0	